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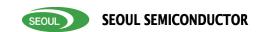
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









X42180-07

Z-Power series is designed for high current operation and high flux output applications.



Z-Power LED's thermal performance exceeds other power LED solutions.

It incorporates state of the art SMD design and Thermal emission material.

Z Power LED is ideal light sources for general illumination applications, custom designed solutions, automotive and large LCD backlights.

X42180-07

Features

- Super high flux output and high luminance
- Designed for high current operation
- Low thermal resistance
- SMT solderable
- Lead free product
- RoHS compliant

Applications

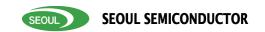
- Mobile phone flash
- Automotive interior / Exterior lighting
- Automotive signal lighting
- Automotive forward lighting
- Torch
- Architectural lighting
- LCD TV / Monitor backlight
- Projector light source
- Traffic signals
- Task lighting
- Decorative / Pathway lighting
- Remote / Solar powered lighting
- Household appliances

*The appearance and specifications of the product may be changed for improvement without notice.

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Full Code of Z-Power LED Series

Full code form: $X_1 X_2 X_3 X_4 X_5 X_6 X_7 - X_8 X_9 - X_{10} X_{11} X_{12} X_{13} X_{14}$

1. Part Number

- X₁: Color
- X₂: Z-Power LED series number
- X₃: LENS type
- X₄: Chip quantity (or Power Dissipation)
- X₅: Package outline size
- X₆: Type of PCB
- X₇: Grade of characteristic code

2. Internal Number

- X₈, X₉: Revision No.

3. Code Labeling

- X₁₀: Luminous flux (or Radiant flux for royal blue)
- X₁₁ X₁₂ X₁₃: Dominant wavelength (or x,y coordinates rank code)
- X₁₄: Forward voltage

4. Sticker Diagram on Reel & Aluminum Vinyl Bag

For more information about binning and labeling, refer to the Application Note -1

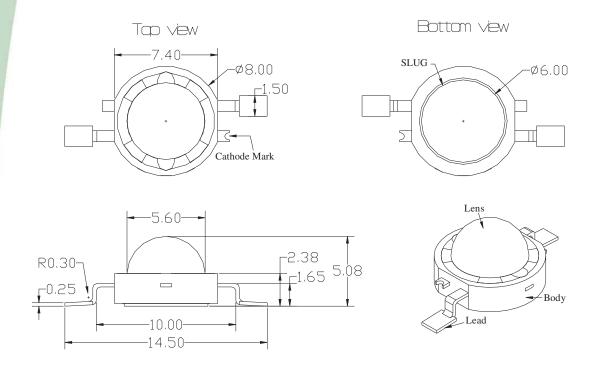
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Outline Dimension

1. Dome Type



Notes:

- 1. All dimensions are in millimeters. (tolerance : ± 0.2)
- 2. Scale : none3. Slug of package is connected to anode.

*The appearance and specifications of the product may be changed for improvement without notice.



1. Pure White (W42180-07)

1-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter		Symbol	Value			Unit
Parameter			Min	Тур	Max	Onit
Luminous Flux [1]	T rank	Φ _V [2]	70	80	91	lm
Luminous Flux [1]	U rank	Φ _V [2]	91	108	118.5	lm
Correlated Color Temper	ature [3]	CCT	-	6300	-	K
CRI		R_a	-	73	-	-
Forward Voltage [4	1]	V_{F}	-	3.1	-	V
View Angle		20 ½		127		deg.
Thermal resistance ^[5]		Rθ _{J-B}	10.1			°C/W
Thermal resistance	[6]	Rθ _{J-C}		8.5		°C/W

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	°C
Operating Temperature	T_{opr}	-40 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	°C
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance.
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5], [6] R $\theta_{\text{J-B}}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{\text{J}} \leq$ 110 °C) R $\theta_{\text{J-C}}$ is measured with only emitter.(25 °C \leq T $_{\text{J}} \leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

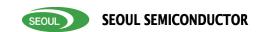
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1. Please do not drive at rated current more than 5 sec. without proper heat sink.

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2. Warm White (N42180-07)

2-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter	Symbol	Value			l l m i d
Farameter		Min	Тур	Max	Unit
Luminous Flux [1]	Φ _V [2]	-	72	-	lm
Correlated Color Temperature [3]	CCT	-	3000	-	К
CRI	R _a	-	93	-	-
Forward Voltage [4]	V_{F}	-	3.1	-	V
View Angle	20 1/2	126		deg.	
Thermal resistance [5]	Rθ _{J-B}	10.1		°C/W	
Thermal resistance [6]	Rθ _{J-C}		8.5		°C/W

2-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	oC.
Operating Temperature	T_{opr}	-40 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	°C
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J} \leq$ 110 °C) $R\theta_{J-C}$ is measured with only emitter.(25 °C \leq T $_{J} \leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

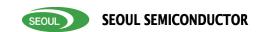
-----Caution-----

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3. Warm White (N42180H-07)

3-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter	Cumbal	Value			Unit
Parameter	Symbol	Min	Тур	Max	Onit
Luminous Flux [1]	Φ _V [2]	-	90	-	lm
Correlated Color Temperature [3]	CCT	-	3000	-	K
CRI	R_a	-	80	-	-
Forward Voltage ^[4]	V_{F}	-	3.1	-	V
View Angle	20 1/2	127		deg.	
Thermal resistance ^[5]	Rθ _{J-B}	10.1		°C /W	
Thermal resistance [6]	Rθ _{J-C}		8.5		°C/W

3-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	oC
Operating Temperature	T_{opr}	-40 ~ +85	oC.
Storage Temperature	T_{stg}	-40 ~ +100	oC.
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an iintegrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance
- [4] A tolerance of $\pm 0.06 \mbox{V}$ on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J} <math>\leq$ 110 °C) $R\theta_{J-C}$ is measured with only emitter.(25 °C \leq T $_{J} <math>\leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

-----Caution-----

1. Please do not drive at rated current more than 5 sec. without proper heat sink

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4. Natural White (S42180-07)

4-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter	Sumbal	Value			Unit
Farameter	Symbol	Min	Тур	Max	Onit
Luminous Flux [1]	Φ _V ^[2]	-	76	-	lm
Correlated Color Temperature [3]	ССТ	-	4000	-	K
CRI	R_a	-	93	-	-
Forward Voltage ^[4]	V_{F}	-	3.1	-	V
View Angle	20 1/2	126		deg.	
Thermal resistance ^[5]	Rθ _{J-B}	10.1		°C/W	
Thermal resistance [6]	Rθ _{J-C}		8.5		°C/W

4-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	oC
Operating Temperature	T_{opr}	-40 ~ +85	oC.
Storage Temperature	T_{stg}	-40 ~ +100	oC.
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance.
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J} \leq$ 110 °C) $R\theta_{J-C}$ is measured with only emitter. (25 °C \leq T $_{J} \leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

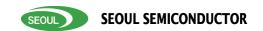
-----Caution-----

1. Please do not drive at rated current more than 5 sec. without proper heat sink

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5. Natural White (S42180H-07)

5-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter	Symbol	Value			Unit
Farameter	Symbol	Min	Тур	Max	Onit
Luminous Flux [1]	Φ _V [2]	-	98	-	lm
Correlated Color Temperature [3]	CCT	-	4000	-	K
CRI	R_a	-	80	-	-
Forward Voltage ^[4]	V_{F}	-	3.1	-	V
View Angle	20 1/2	127		deg.	
Thermal resistance ^[5]	Rθ _{J-B}	10.1		°C/W	
Thermal resistance ^[6]	Rθ _{J-C}		8.5		°C/W

5-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	oC
Operating Temperature	T_{opr}	-40 ~ +85	oC.
Storage Temperature	T_{stg}	-40 ~ +100	oC.
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance.
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J} \leq$ 110 °C) $R\theta_{J-C}$ is measured with only emitter. (25 °C \leq T $_{J} \leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

-----Caution-----

1. Please do not drive at rated current more than 5 sec. without proper heat sink

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6. Blue (B42180-07)

6-1 Electro-Optical characteristics at I_F=350mA, T_A=25°C

Parameter	Symbol	Value			Unit
Farameter	Symbol	Min	Тур	Max	Ollit
Luminous Flux [1]	Φ _V [2]	-	22	-	lm
Dominant Wavelength ^[3]	λ_{D}	455	465	475	nm
Forward Voltage ^[4]	V_{F}	-	3.2	-	V
View Angle	20 1/2		130		deg.
Thermal resistance [5]	Rθ _{J-B}		10.1		°C/W
Thermal resistance ^[6]	Rθ _{J-C}		8.5		°C/W

6-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	${ m I}_{\sf F}$	800	mA
Power Dissipation	P_d	3.28	W
Junction Temperature	T _j	145	oC
Operating Temperature	T_{opr}	-40 ~ +85	oC
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Dominant wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J} \leq$ 110 °C) $R\theta_{J-C}$ is measured with only emitter.(25 °C \leq T $_{J} \leq$ 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

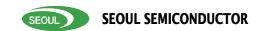
-----Caution-----

- 1. Please do not drive at rated current more than 5 sec. without proper heat sink
- 2. Blue power light sources represented here are in risk group2(Medium) according to IEC 62471

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7. Royal Blue (D42180-07)

7-1 Electro-Optical characteristics at $I_F=350$ mA, $T_A=25$ °C

Parameter	Symbol	Value			Unit
		Min	Тур	Max	Onit
Radiant Power [1]	Φ _V [2]	-	468	-	mW
Dominant Wavelength [3]	λ_{D}	455	457	460	nm
Forward Voltage ^[4]	V_{F}	-	3.2	-	V
View Angle	20 1/2		130		deg.
Thermal resistance [5]	Rθ _{J-B}		10.1		°C /W
Thermal resistance ^[6]	Rθ _{J-C}		8.5		°C /W

7-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	
Forward Current	${ m I}_{ m F}$	800	mA	
Power Dissipation	P _d	3.28	W	
Junction Temperature	T_{j}	145	°C	
Operating Temperature	T_{opr}	-40 ~ +85	°C	
Storage Temperature	T _{stg}	-40 ~ +100	°C	
ESD Sensitivity [7]	-	$\pm 10,000$ V HBM	-	

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_{V} is the total Radiant power output as measured with anintegrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ tester tolerance
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5], [6] $R\theta_{J-B}$ is measured with a SSC metal core pcb.(25 °C \leq T $_{J}$ \leq 110 °C) $R\theta_{J-C}$ is measured with only emitter.(25 °C \leq T $_{J}$ \leq 110 °C)
- [7] It is included the zener chip to protect the product from ESD.

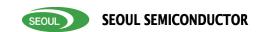
-----Caution-----

- 1. Please do not drive at rated current more than 5 sec. without proper heat sink
- 2. Blue power light sources represented here are in risk group2(Medium) according to IEC 62471

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8. Photosynthetic Red (P42180-07)

11-1 Electro-Optical characteristics at I_F =350mA, T_A =25°C

Parameter	Symbol	Value			Unit
		Min	Тур	Max	Unit
Radiant Power [1]	Φ _V ^[2]	150	240	280	mW
Peak Wavelength ^[3]	λ_{P}	655	660	665	nm
Forward Voltage ^[4]	V_{F}	2.0	2.4	3.0	V
View Angle	20 1/2		130		deg.
Thermal resistance [5]	Rθ _{J-C}		9	·	°C/W

11-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_{F}	700	mA
Power Dissipation	P_d	2.1	W
Junction Temperature	T_{j}	125	oC
Operating Temperature	T_{opr}	-40 ~ +85	oC
Storage Temperature	T_{stg}	-40 ~ +100	°C
ESD Sensitivity [6]	-	$\pm 10,000$ V HBM	-

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] Φ_V is the total Radiant power output as measured with an integrating sphere.
- [3] Peak wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 1 nm for peak wavelength
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5] $R\theta_{\mbox{\scriptsize J-C}}$ is measured with only emitter.
- [6] It is included the zener chip to protect the product from ESD.

-----Caution-----

1. Please do not drive at rated current more than 5 sec. without proper heat sink

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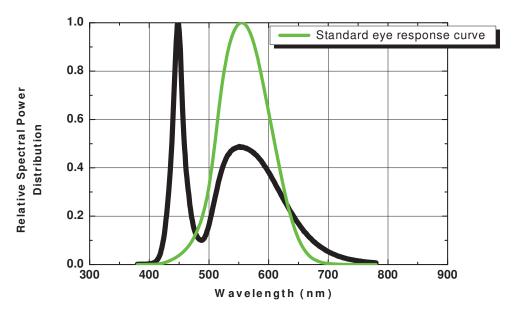
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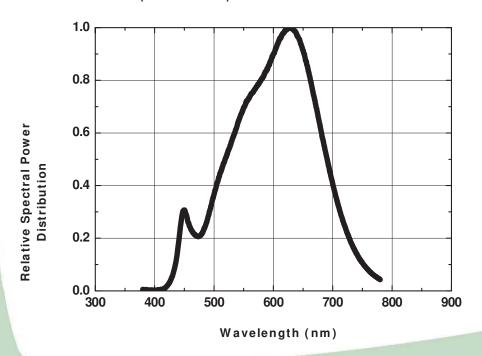


Color Spectrum, T_A= 25 º C

1. Pure White(W42180-07)



2. Warm White (N42180-07)



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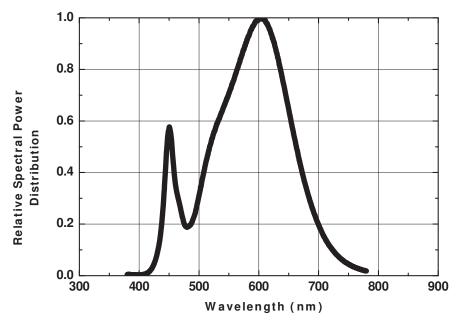
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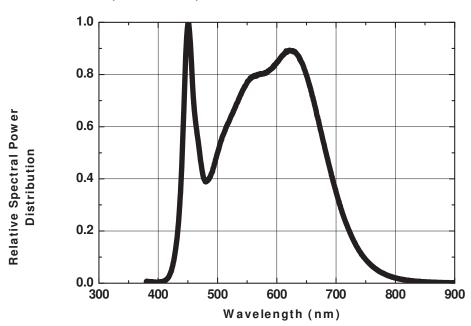


Color Spectrum, T_A= 25 º C

3. Warm White (N42180H-07)



4. Natural White (S42180-07)



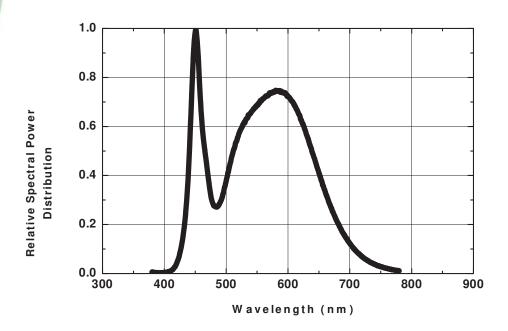
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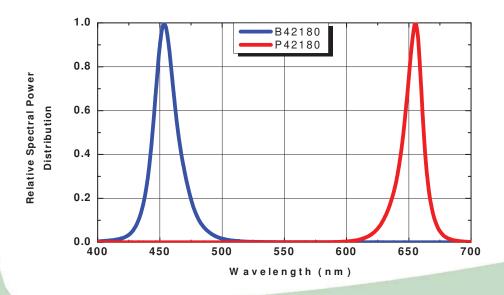


Color Spectrum, T_A= 25 º C

5. Natural White (S42180H)



6. Blue(Royal Blue), Photosynthetic Red



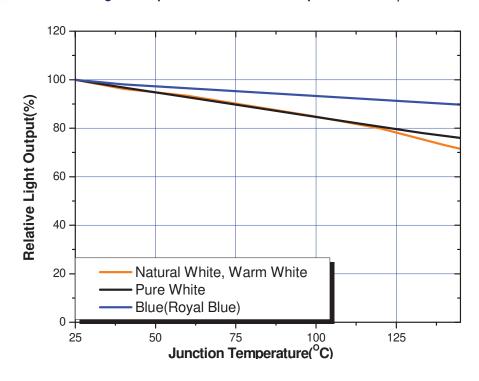
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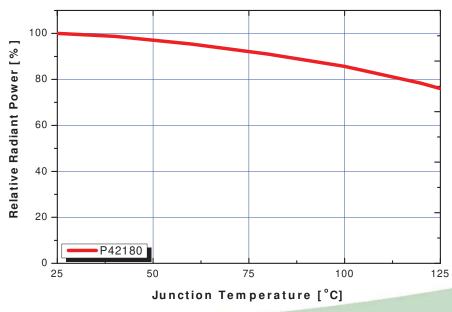
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Junction Temperature Characteristics

1. Relative Light Output vs. Junction Temperature at $I_F = 350 \, \text{mA}$





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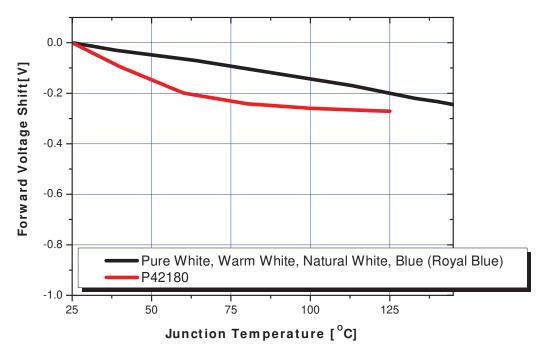
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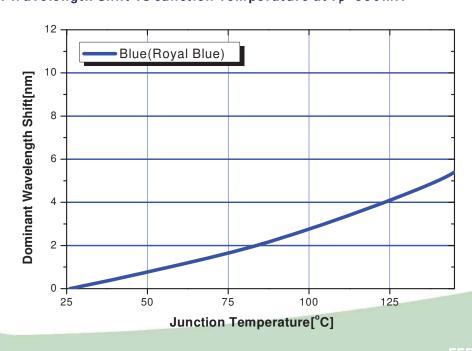


Junction Temperature Characteristics

2. Forward Voltage Shift vs. Junction Temperature at I $_{\rm F}$ = 350 mA



3. Wavelength Shift vs Junction Temperature at I $_{\text{F}}$ = 350 mA



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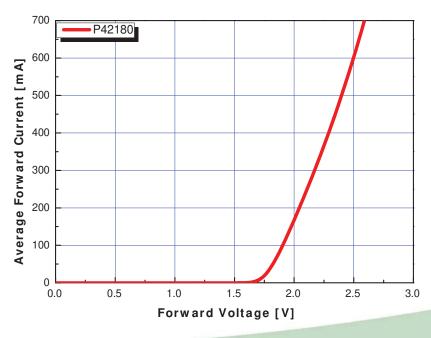
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Forward Current Characteristics

1. Forward Voltage vs. Forward Current , $T_A = 25$ $^{\circ}$ c





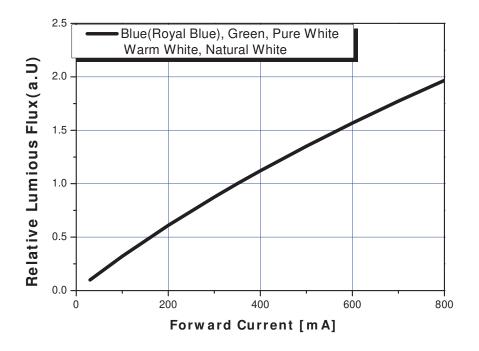
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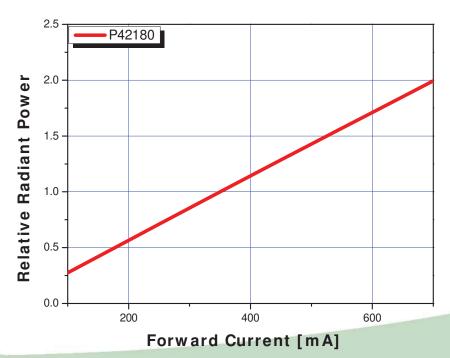
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Forward Current Characteristics

2. Forward Current vs. Normalized Relative Luminous Flux, $\rm T_A$ = 25 $^{\circ}\,c$





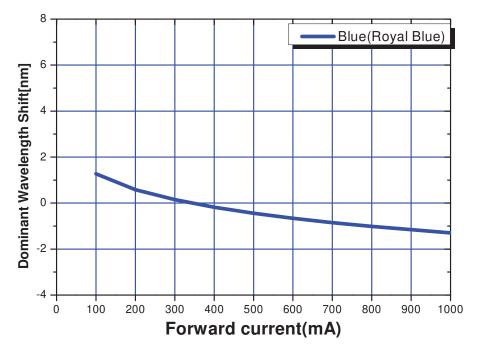
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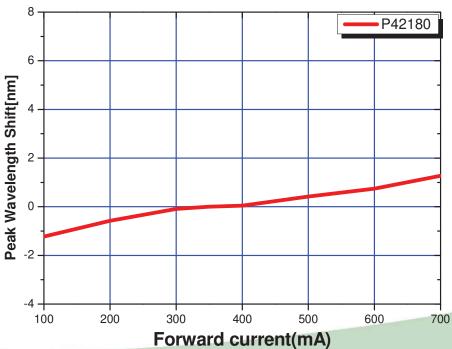
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Forward Current Characteristics

3. Forward Current vs Wavelength Shift, T_A = 25 $^{\circ}$ c





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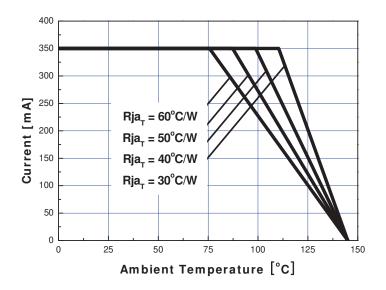
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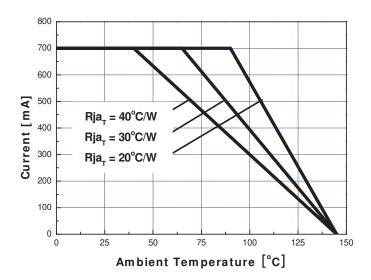


Ambient Temperature vs Allowable Forward Current

1-1. Pure White, Warm White, Natural White, Blue(Royal Blue) (T.MAX = 145 °C, @350 m A)



1-2. Pure White, Warm White, Natural White, Blue (Royal Blue) (T....x = 145 °C, @700 m A)



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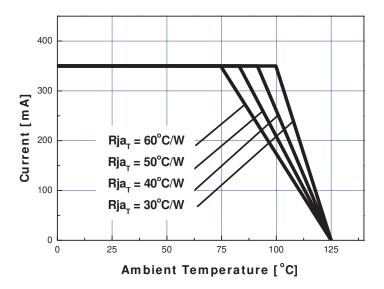
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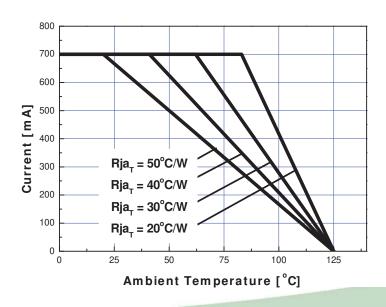


Ambient Temperature vs Allowable Forward Current

1-3. Photosynthetic Red ($T_{JMAX} = 125 \, {}^{\circ}\text{C}$, at 350 m A)



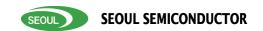
1-4. Photosynthetic Red $(T_{JMAX} = 125 \, {}^{\circ}C, \, @700 \, mA)$



Rev. 20

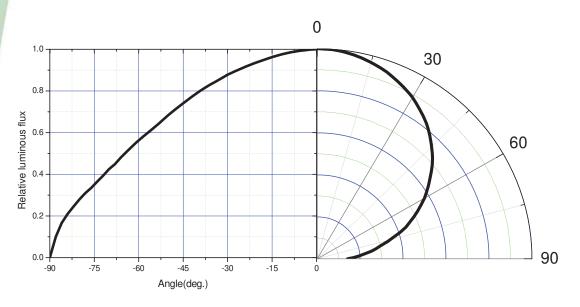
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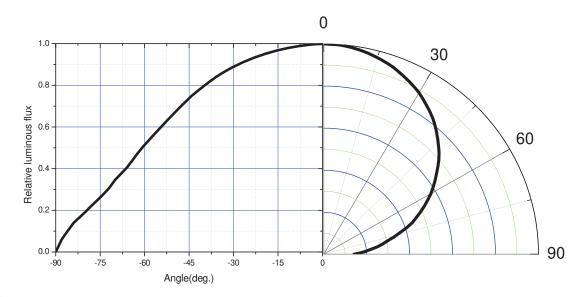


Typical Dome Type Radiation pattern

1. Pure White



2. Warm White, Natural White



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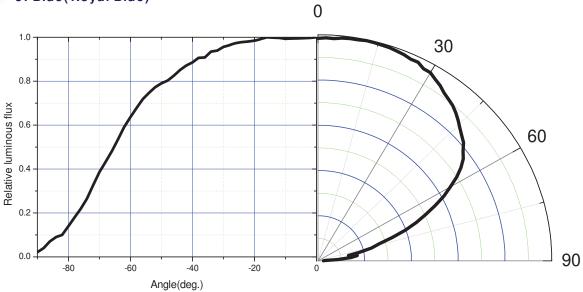
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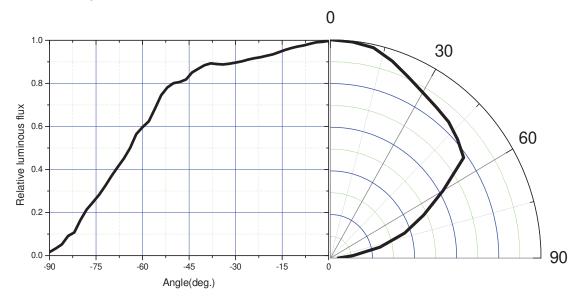


Typical Dome Type Radiation pattern

3. Blue(Royal Blue)



4. Photosynthetic Red



Rev. 20

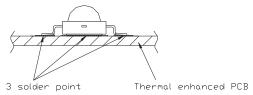
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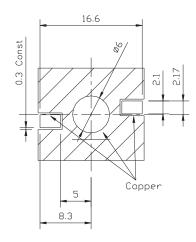
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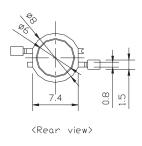


Recommended Solder pad

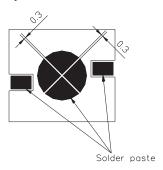
1. Solder pad







2. Solder paste pattern



Note:

- 1. All dimensions are in millimeters (tolerance : ± 0.2)
- 2. Scale none

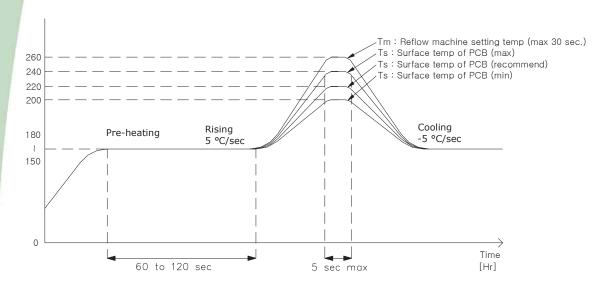
*The appearance and specifications of the product may be changed for improvement without notice.

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3. Reflow Soldering Conditions / Profile



4. Hand Soldering conditions

Lead: Not more than 3 seconds @MAX280 ℃

Slug: Use a thermal-adhesives

* Caution

- 1. Reflow soldering should not be done more than one time.
- 2. Repairing should not be done after the LEDs have been soldered. When repairing is unavoidable, suitable tools have to be used.
- 3. The bottom of the emiter is to be soldered.
- 4. When soldering, do not put stress on the LEDs during heating.
- 5. After soldering, do not warp the circuit board.
- 6. Recommend to use a convection type reflow machine with 7 \sim 8 zones.

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